

NPN Epitaxial Silicon Transistor

KSC945

Features

- Audio Frequency Amplifier and High-Frequency OSC
- Complimentary to KSA733
- Collector-Base Voltage: $V_{CBO} = 60\text{ V}$
- High Current Gain Bandwidth Product: $f_T = 300\text{ MHz}$ (Typical)
- Suffix “-C” Means Center Collector
(1. Emitter 2. Collector 3. Base)

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Symbol	Parameter	Ratings	Unit
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	150	mA
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 to 150	$^\circ\text{C}$

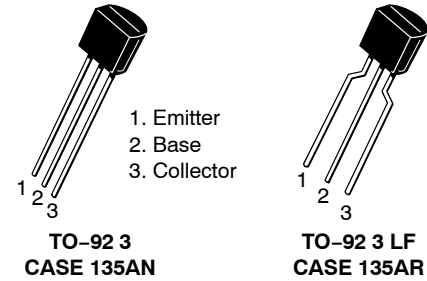
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

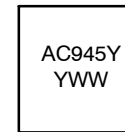
($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Symbol	Parameter	Value	Unit
P_D	Power Dissipation	250	mW
	Derate Above 25°C	2.0	mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	500	$^\circ\text{C}/\text{W}$

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



MARKING DIAGRAM



A = Assembly Site
C945Y = Specific Device Code
Y = Year of Production
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
KSC945CYTA	TO-92 3 LF (Pb-Free)	2,000 Units / FNFLD
KSC945YTA	TO-92 3 LF (Pb-Free)	2,000 Units / FNFLD

DISCONTINUED (Note 1)

KSC945YBU	TO-92 3 (Pb-Free)	10,000 Units / Bulk
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1. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on www.onsemi.com.

KSC945

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
BV_{CBO}	Collector–Base Breakdown Voltage	$I_C = 100\ \mu\text{A}$, $I_E = 0$	60	–	–	V
BV_{CEO}	Collector–Emitter Breakdown Voltage	$I_C = 10\ \text{mA}$, $I_B = 0$	50	–	–	V
BV_{EBO}	Emitter–Base Breakdown Voltage	$I_E = 10\ \mu\text{A}$, $I_C = 0$	5	–	–	V
I_{CBO}	Collector Cut–Off Current	$V_{CB} = 40\ \text{V}$, $I_E = 0$	–	–	0.1	μA
I_{EBO}	Emitter Cut–Off Current	$V_{EB} = 3\ \text{V}$, $I_C = 0$	–	–	0.1	μA
h_{FE}	DC Current Gain	$V_{CE} = 6\ \text{V}$, $I_C = 1.0\ \text{mA}$	120	–	240	
$V_{CE(sat)}$	Collector–Emitter Saturation Voltage	$I_C = 100\ \text{mA}$, $I_B = 10\ \text{mA}$	–	0.15	0.30	V
f_T	Current Gain Bandwidth Product	$V_{CE} = 6\ \text{V}$, $I_C = 10\ \text{mA}$	–	300	–	MHz
C_{ob}	Output Capacitance	$V_{CB} = 6\ \text{V}$, $I_E = 0$, $f = 1\ \text{MHz}$	–	2.5	–	pF
NF	Noise Figure	$V_{CE} = 6\ \text{V}$, $I_C = 0.5\ \text{mA}$, $f = 1\ \text{kHz}$, $R_S = 500\ \Omega$	–	4.0	–	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

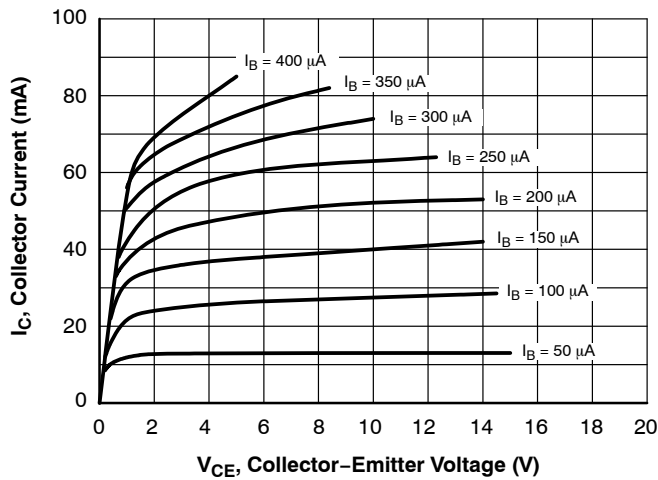


Figure 1. Static Characteristic

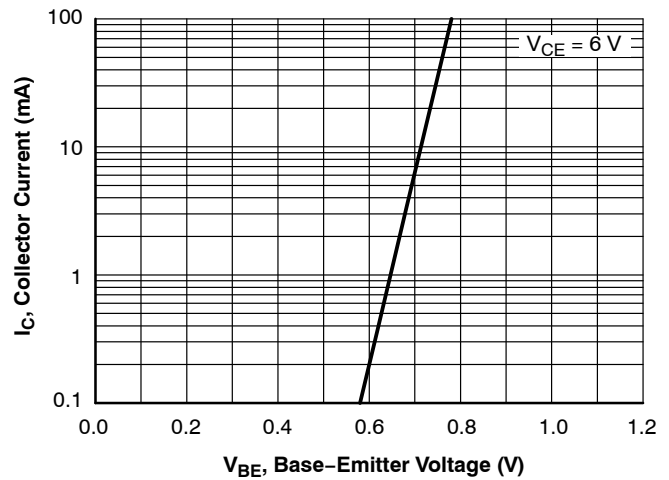


Figure 2. Transfer Characteristic

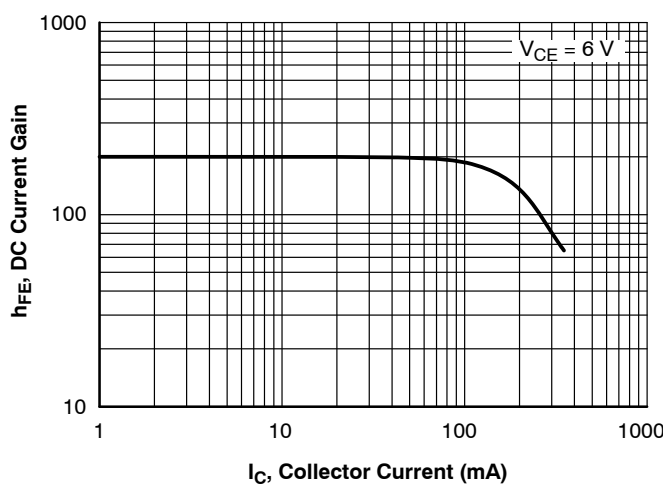


Figure 3. DC Current Gain

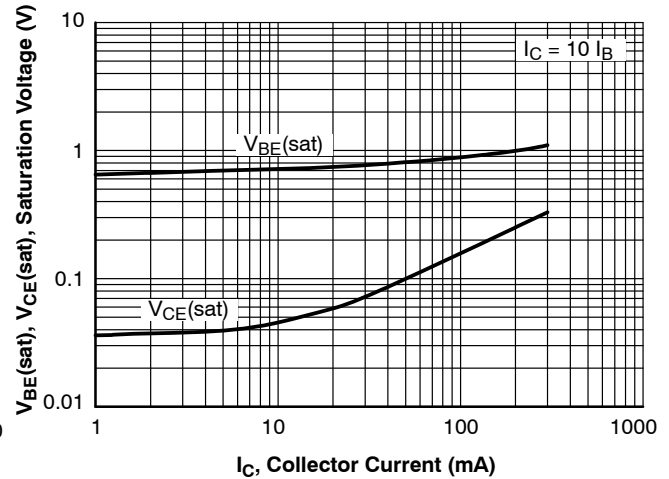


Figure 4. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

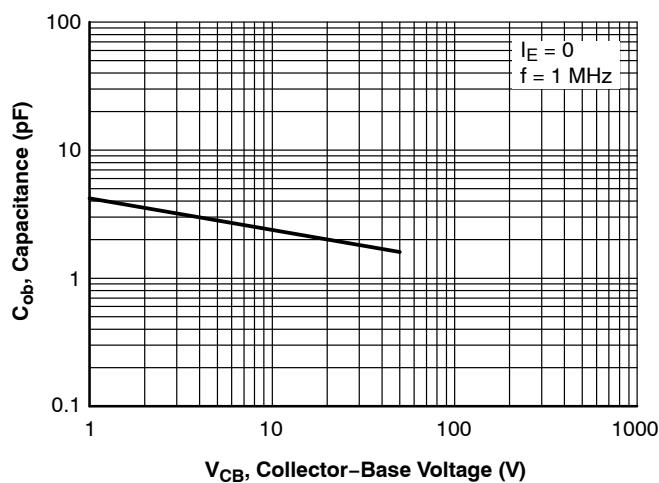


Figure 5. Output Capacitance

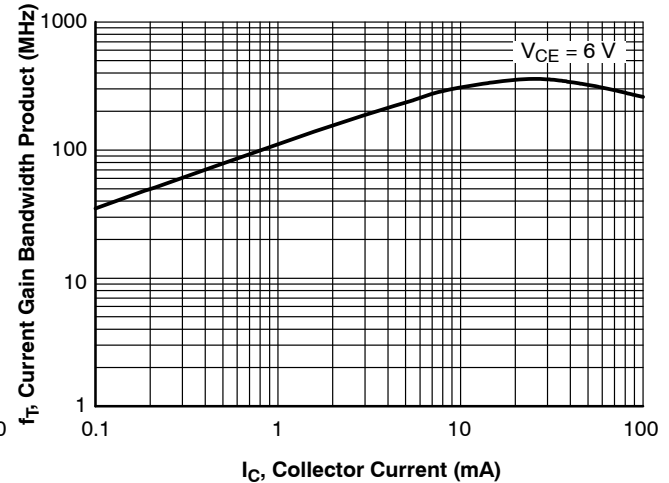


Figure 6. Current Gain Bandwidth Product

MECHANICAL CASE OUTLINE

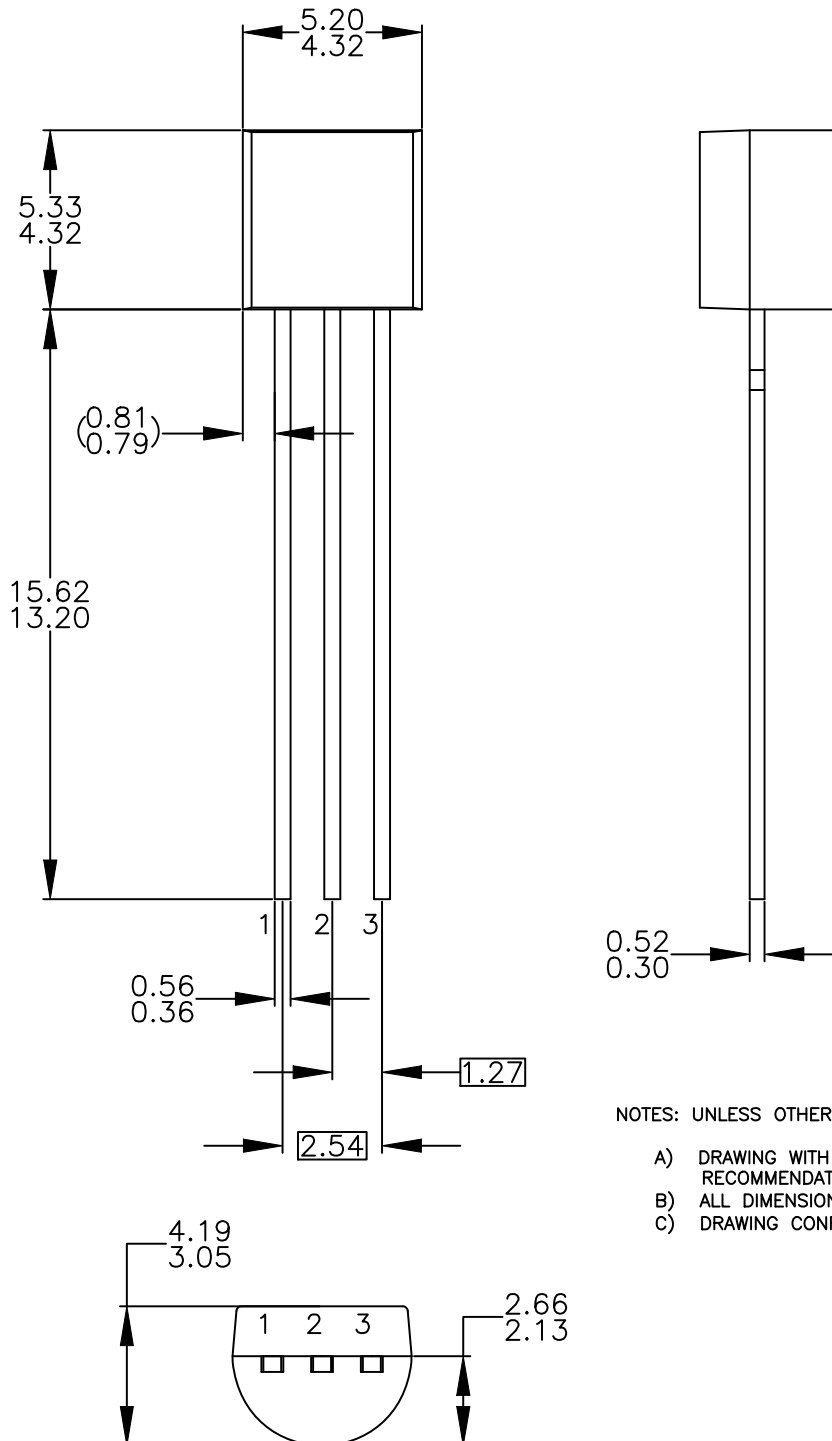
PACKAGE DIMENSIONS

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ON

TO-92 3 4.825x4.76
CASE 135AN
ISSUE O

DATE 31 JUL 2016



NOTES: UNLESS OTHERWISE SPECIFIED

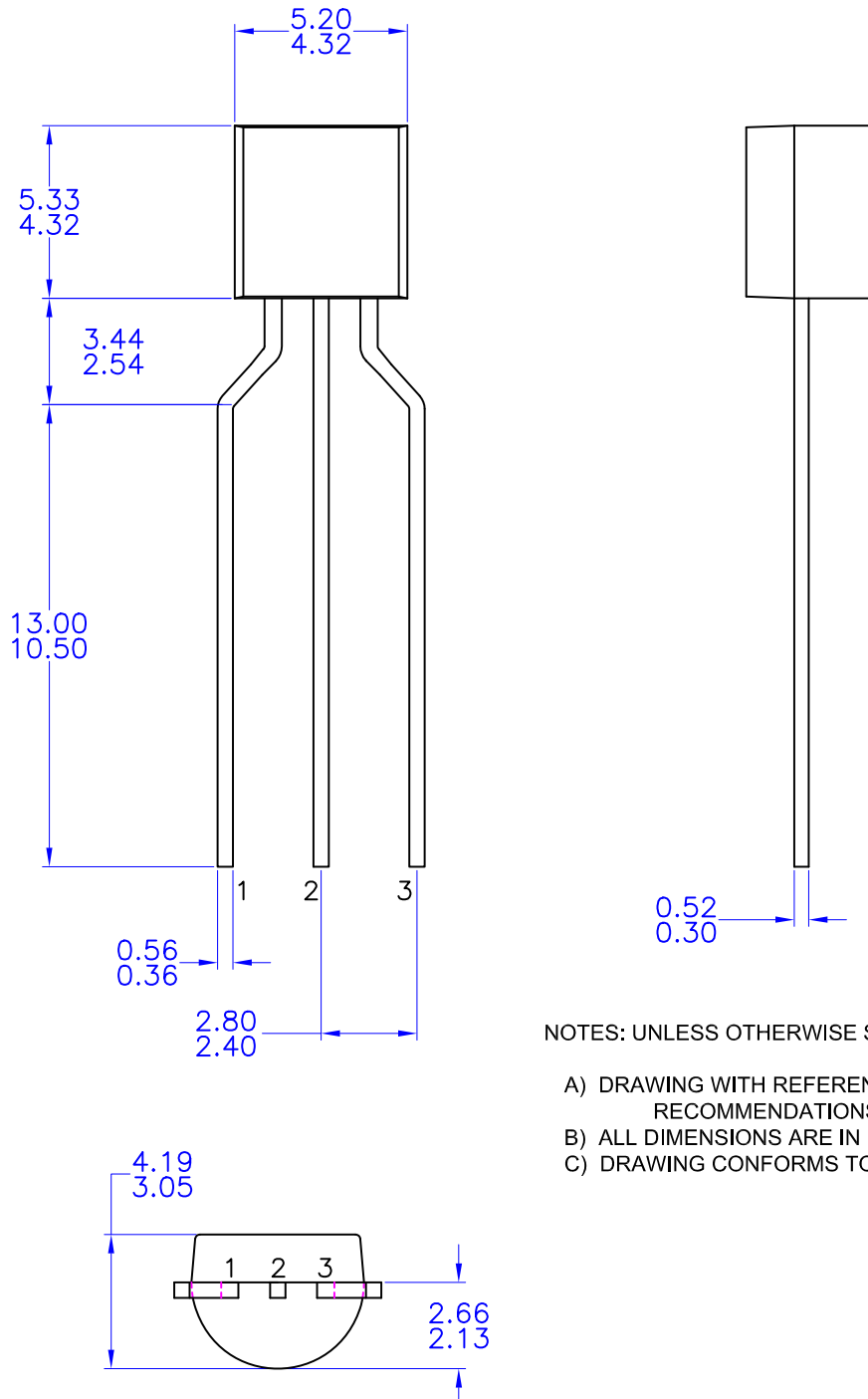
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